



SHEET OF

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 242330US2S		SERIAL NO. 10/653,976	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Kentaro NAKAJIMA			
				FILING DATE September 4, 2003		GROUP 2818	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
Uet	AA	6,473,336	10/29/02	NAKAJIMA et al.	—	—	—
	AB						
	AC						
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FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
	AQ						
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	AS						
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	AU						
	AV						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
	AW						
	AX						
	AY						
	AZ						
					<input type="checkbox"/> Additional References sheet(s) attached		
Examiner LONG TRIM					Date Considered 11/5/05		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							



SHEET 1 OF 1

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(Modified)U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

ATTY DOCKET NO.

242330US2S

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LIST OF REFERENCES CITED BY APPLICANT

APPLICANT

Kentaro NAKAJIMA

FILING DATE

September 4, 2003

GROUP

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
Ukr	AA	6,429,044	08/06/2002	M. TUTTLE	—	—	—
Ukr	AB	5,939,772	08/17/1999	A. T. HURST, et al.	—	—	—
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FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION	
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	AO					
	AP					
	AQ					
	AR					
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	AT					
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OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

Ukr	AW	R. SCHEUERLEIN, et al., IEEE International Solid-State Circuits Conference, ISSCC 2000 / Session 7/ TD: Emerging Memory & Device Technologies / Paper 7.2, pages 128-129, "TA 7.2 A 10ns READ AND WRITE NON-VOLATILE MEMORY ARRAY USING A MAGNETIC TUNNEL JUNCTION AND FET SWITCH IN EACH CELL", 2000				
Ukr	AX	M. SATO, et al., IEEE Transactions on Magnetics, vol. 33, no. 5, pages 3553-3555, "SPIN-VALVE-LIKE PROPERTIES AND ANNEALING EFFECT IN FERROMAGNETIC TUNNEL JUNCTIONS", September 1997				
Ukr	AY	M. SATO, et al., Jpn. J. Appl. Phys, vol. 36, part 2, no. 28, pages L200-L201, "SPIN-VALVE-LIKE PROPERTIES OF FERROMAGNETIC TUNNEL JUNCTIONS", February 15, 1997				
Ukr	AZ	K. INOMATA, et al., Jpn. J. Appl. Phys, vol. 36, part 2, no. 108, pages L 1380-L 1383, "SPIN-DEPENDENT TUNNELING BETWEEN A SOFT FERROMAGNETIC LAYER AND HARD MAGNETIC NANOSIZE PARTICLES", October 15, 1997				<input type="checkbox"/> Additional References sheet(s) attached

Examiner

LONG TRAM

Date Considered

4/5/05

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